2SC6043

Bipolar Transistor 50V, 2A, Low VCE(sat) NPN Single MP



http://onsemi.com

Applications

• Voltage regulators, relay drivers, lamp drivers, electrical equipment

Features

- Adoption of MBIT process
- High current capacitance

- Low collector to emitter saturation voltage
- High-speed switching

Specifications

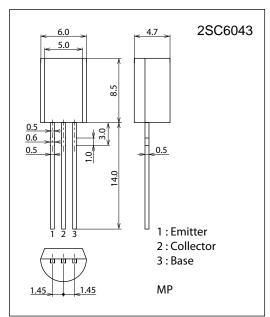
Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|------------|-------------|------|
| Collector to Base Voltage | VCBO | | 80 | V |
| Collector to Emitter Voltage | VCES | | 80 | V |
| Collector to Emitter Voltage | VCEO | | 50 | V |
| Emitter to Base Voltage | V _{EBO} | | 6 | V |
| Collector Current | IC | | 2 | Α |
| Collector Current (Pulse) | ICP | | 4 | Α |
| Base Current | IB | | 400 | mA |
| Collector Dissipation | PC | | 1 | W |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7520-002



Product & Package Information

• Package : MP

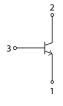
• JEITA, JEDEC : SC-51, TO-92(1-WATT), TO-226AE

• Minimum Packing Quantity : 1,000 pcs./box

Marking

C6043

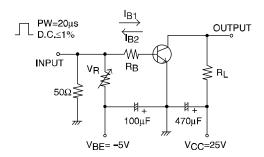
Electrical Connection



Electrical Characteristics at Ta = 25°C

| Description | Symbol | O and distinct | Ratings | | | 1.1:4 |
|---|-----------------------|---|---------|------|-----|-------|
| Parameter | | Conditions | min | typ | max | Unit |
| Collector Cutoff Current | ICBO | V _{CB} =40V, I _E =0A | | | 1 | μА |
| Emitter Cutoff Current | I _{EBO} | V _{EB} =4V, I _C =0A | | | 1 | μΑ |
| DC Current Gain | hFE1 | V _{CE} =2V, I _C =100mA | 200 | | 560 | |
| | hFE2 | V _{CE} =2V, I _C =1.5A | 40 | | | |
| Gain-Bandwidth Product | fT | V _{CE} =10V, I _C =300mA | | 420 | | MHz |
| Output Capacitance | Cob | V _{CB} =10V, f=1MHz | | 9 | | pF |
| Collector to Emitter Saturation Voltage | V _{CE} (sat) | I _C =1A, I _B =50mA | | 150 | 300 | mV |
| Base to Emitter Saturation Voltage | V _{BE} (sat) | I _C =1A, I _B =50mA | | 0.94 | 1.2 | V |
| Collector to Base Breakdown Voltage | V(BR)CBO | I _C =10μA, I _E =0A | 80 | | | V |
| Collector to Emitter Breakdown Voltage | V(BR)CES | I _C =100μA, R _{BE} =0Ω | 80 | | | V |
| Collector to Emitter Breakdown Voltage | V(BR)CEO | I _C =1mA, R _{BE} =∞ | 50 | | | V |
| Emitter to Base Breakdown Voltage | V(BR)EBO | I _E =10μA, I _C =0A | 6 | | | V |
| Turn-ON Time | ton | | | 35 | | ns |
| Storage Time | t _{stg} | See specified Test Circuit | | 330 | _ | ns |
| Fall Time | tf | | | 40 | | ns |

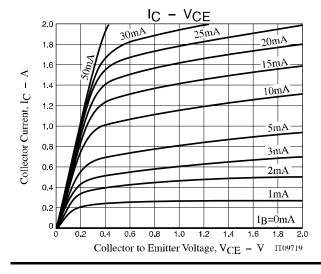
Switching Time Test Circuit

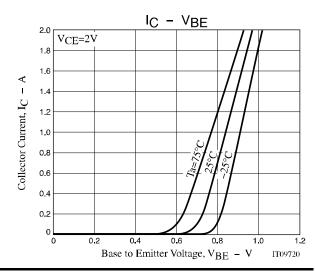


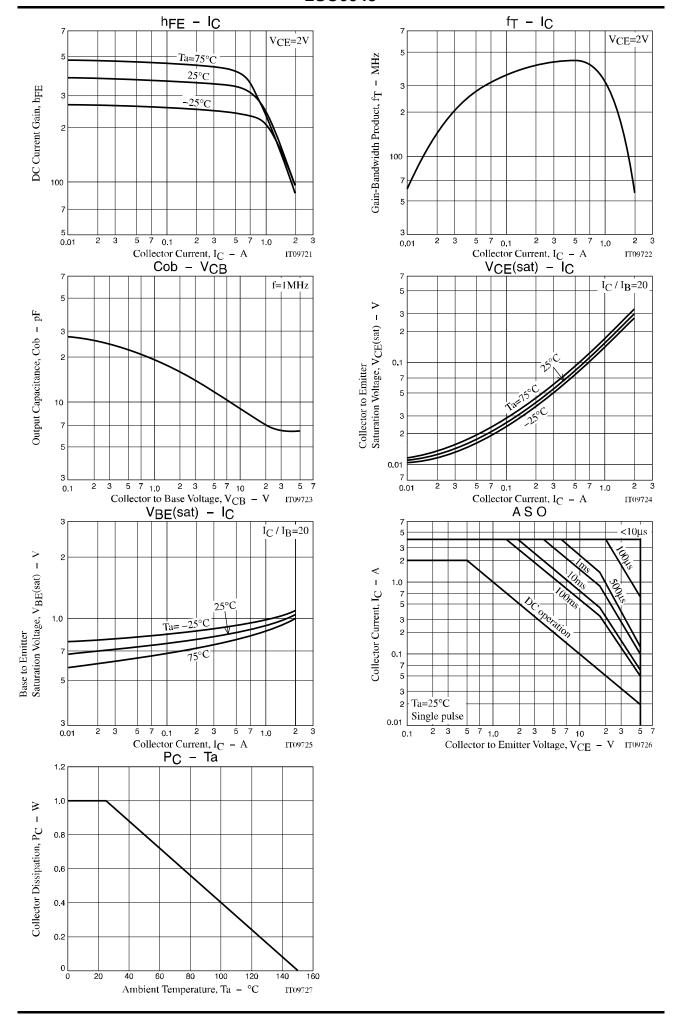
 $I_{C}=10I_{B1}=-10I_{B2}=700mA$

Ordering Information

| Device | Package | Shipping | Memo |
|------------|---------|---------------|---------|
| 2SC6043 | MD | 500pcs./bag | Dh. E |
| 2SC6043-AE | MP | 1,000pcs./box | Pb Eree |

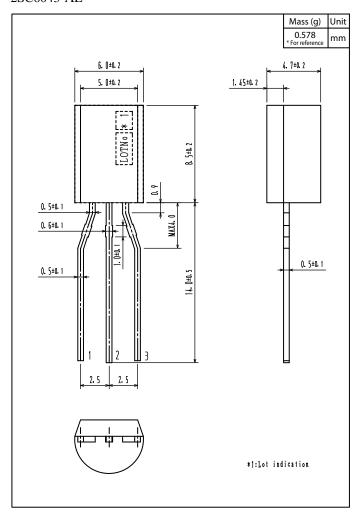






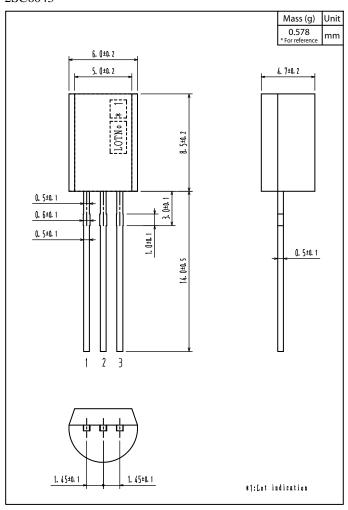
Outline Drawing

2SC6043-AE



Outline Drawing

2SC6043



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